

4.5 V to 36 V Input, 5 A Integrated MOSFET Single Synchronous Buck DC/DC Converter

BD9F500QUZ

General Description

BD9F500QUZ is a synchronous buck DC/DC converter with built-in low on-resistance power MOSFETs. It is capable of providing current up to 5 A. It features fast transient response due to Constant On-Time control system. The Light Load Mode control improves efficiency in light-load conditions. It is ideal for reducing standby power consumption of equipment. Power Good function makes it possible for system to control sequence. It achieves the high power density and offer a small footprint on the PCB by employing small package.

Features

- Single Synchronous Buck DC/DC Converter
- Constant On-Time Control
- Light Load Mode Control
- Adjustable Soft Start
- Power Good Output
- Nano Pulse Control™
- Output Capacitor Discharge Function
- Over Voltage Protection (OVP)
- Over Current Protection (OCP)
- Short Circuit Protection (SCP)
■ Thermal Shutdown Protection
- Thermal Shutdown Protection (TSD)
- Under Voltage Lockout Protection (UVLO)
- VMMP16LZ3030 Package Backside Heat Dissipation, 0.5 mm Pitch

Applications

- Step-down Power Supply for SoC, FPGA, Microprocessor
- **Printer (MFP / LBP / IJP / POS)**
- OA Equipment
- **Laptop PC**
- USB Type-C Applications

Typical Application Circuit

VIN BOOT **BD9F500QUZ** SW FB V_{OUT} L VREG 0.1 μF C_{REG} $\left.\right|$ SS AGND PGD SEL1 C_{OUT} **C_{IN}** R_1 $R₂$ SEL2 PGND V_{IN} C_{FB} $\frac{V_{EN}}{V_{EN}}$ EN $V_{\rm SEL}$ V_{SEL2}

Nano Pulse Control™ is a trademark or a registered trademark of ROHM Co., Ltd.

〇Product structure : Silicon integrated circuit 〇This product has no designed protection against radioactive rays.

SS

Key Specifications

Package W (Typ) x D (Typ) x H (Max) VMMP16LZ3030 3.0 mm x 3.0 mm x 0.40 mm

VMMP16LZ3030

Pin Configuration

Pin Descriptions

Block Diagram

Description of Blocks

1. VREF

This block generates the internal reference voltage.

2. REG

This block generates the internal power supply.

3. Soft Start

The Soft Start circuit slows down the rise of output voltage during start-up and controls the current, which allows the prevention of output voltage overshoot and inrush current. The internal soft start time is 2 ms (Typ) when the SS pin is open. A capacitor connected to the SS pin makes the rising time more than 2 ms.

4. Error Amplifier

The Error Amplifier adjusts the Main Comparator input voltage to make the internal reference voltage equal to FB voltage.

5. Main Comparator

The Main Comparator compares the Error Amplifier output voltage and FB voltage (V_{FB}). When V_{FB} becomes lower than the Error Amplifier output voltage, the output turns high and reports to the On-Time block that the output voltage has dropped below the control voltage.

6. On-Time

This block generates On-Time. The designed On-Time is generated after the Main Comparator output turns high.

7. PGOOD

The PGOOD block is for power good function. When the output voltage reaches within ± 7 % (Typ) of the setting voltage, the built-in open drain Nch MOSFET connected to the PGD pin is turned off and the PGD pin becomes Hi-Z (High impedance). When the output voltage reaches outside $±10$ % (Typ) of the setting voltage, the open drain Nch MOSFET is turned on and PGD pin is pulled down with 500 Ω (Typ).

8. UVLO

The UVLO block is for under voltage lockout protection. The device is shutdown when input voltage (V_{IN}) falls to 4.0 V (Typ) or less. The threshold voltage has the 200 mV (Typ) hysteresis.

9. TSD

The TSD block is for thermal protection. The device is shutdown when the junction temperature Tj reaches to 175 °C (Typ) or more. The device is automatically restored to normal operation with a hysteresis of 25 °C (Typ) when the Tj goes down.

10. OVP

The OVP block is for output over voltage protection. When the FB voltage (V_{FB}) exceeds 120 % (Typ) or more of FB threshold voltage V_{FBTH}, the SW pin is pulled down with 400 Ω (Typ). After V_{FB} falls 115 % (Typ) or less of V_{FBTH}, the device is returned to normal operation condition.

11. HOCP

This block is for over current protection of the High-Side FET. When the current that flows through the High-Side FET reaches the value of over current limit, it turns off the High-Side FET and turns on the Low-Side FET.

12. LOCP

This block is for over current protection of the Low-Side FET. While the current that flows through the Low-Side FET over the value of over current limit, the condition that being turned on the Low-Side FET is continued.

13. SCP

This block is for short circuit protection. After soft start is completed and in condition where V_{FB} is 90 % (Typ) of 0.6 V or less, this block counts the number of times of which current flowing in the Low-Side FET reaches over current limit. When 128 times is counted, the device is shutdown for 16 times of soft start time (Typ) and re-operates.

14. ZX/ROCP

The ZX/ROCP is a comparator that monitors the inductor current. When inductor current falls below 0 A (Typ) while the Low-Side FET is on, it turns off the Low-Side FET (Light Load Mode). When the current that flows through the Low-Side FET reaches the value of over current limit, it turns off the Low-Side FET (Fixed PWM Mode).

15. Control Logic

The Control Logic controls the switching operation and protection function operation.

16. SELECTOR

This block controls switching frequency, maximum output current, and operating mode.

Absolute Maximum Ratings (Ta = 25 °C)

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Thermal Resistance*(Note 1)*

(Note 1) Based on JESD51-2A (Still-Air). *(Note 2)* The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 3) Using a PCB board based on JESD51-3.

(Note 4) Using a PCB board based on JESD51-5, 7.

(Note 5) This thermal via connects with the copper pattern of all layers.

Recommended Operating Conditions

(Note 1) Tj must be 150 °C or less under the actual operating environment. Life time is derated at junction temperature greater than 125 °C.

(Note 2) The maximum value of the output current is determined by the control mode selection.

(Note 3) The switching frequency is reduced as needed to always ensure a proper regulation at low duty and high duty cycles. Use under the condition of V_{OUT} ≤ $V_{IN} \times 0.8$ [V].

Electrical Characteristics (Unless otherwise specified Ta = 25 °C, VIN = 12 V, VEN = 3 V)

(Note 4) No tested on outgoing inspection.

Electrical Characteristics – continued (Unless otherwise specified Ta = 25 °C, V_{IN} = 12 V, V_{EN} = 3 V)

(Note 1) No tested on outgoing inspection.

Figure 1. Shutdown Current vs Temperature Figure 2. Operating Quiescent Current vs Temperature

Figure 3. UVLO Threshold Voltage vs Temperature Figure 4. EN Threshold Voltage vs Temperature

Figure 5. EN Input Current vs Temperature Figure 6. VREG Shutdown Voltage vs Temperature

Figure 7. VREG Output Voltage vs Temperature Figure 8. FB Threshold Voltage vs Temperature

Figure 9. FB Input Current vs Temperature Figure 10. Soft Start Time vs Temperature

Figure 11. Soft Start Charge Current vs Temperature Figure 12. SEL1, SEL2 High Threshold Voltage vs

Temperature

Figure 13. SEL1, SEL2 Low Threshold Voltage vs **Temperature**

Figure 15. High-Side FET ON Resistance1 vs Temperature Figure 16. High-Side FET ON Resistance2 vs Temperature

Figure 20. Switching Frequency vs Temperature (V_{IN} = 12 V, V_{OUT} = 3.3 V, I_{OUT} = 2 A, 1 MHz_ I_{OUTMAX} = 5 A_PWM setting)

Figure 21. Switching Frequency vs Temperature (V_{IN} = 12 V, V_{OUT} = 3.3 V, I_{OUT} = 2 A, 2.2 MHz setting)

Figure 22. Power Good / Fault Threshold Voltage vs **Temperature**

1000 V_{IN} = 12 V PGD MOSFET ON Resistance: R_{PGD} [0] 900 PGD MOSFET ON Resistance : R_{PGD} [Ω] 800 700 600 500 400 300 200 100 0 -40 -20 0 20 40 60 80 Temperature : Ta [°C]

Figure 23. PGD Output Leakage Current vs Temperature Figure 24. PGD MOSFET ON Resistance vs Temperature

Figure 25. Start-up at No Load: $V_{EN} = 0$ V to 5 V (V_{IN} = 12 V, V_{OUT} = 3.3 V, C_{SS} = OPEN, 1 MHz $_l_{\text{OUTMAX}}$ = 5 A $_l_{\text{LLM}}$ setting)

Figure 26. Shutdown at No Load: $V_{EN} = 5 V$ to 0 V (V_{IN} = 12 V, V_{OUT} = 3.3 V, C_{SS} = OPEN, 1 MHz $_l_{\text{OUTMAX}}$ = 5 A $_l_{\text{LLM}$ setting)

Figure 27. Start-up at $R_{LOAD} = 0.66$ Ω: $V_{EN} = 0$ V to 5 V $(V_{IN} = 12 V, V_{OUT} = 3.3 V, C_{SS} = \overrightarrow{OPEN},$ 1 MHz $_l$ loutmax = 5 A $_l$ LLM setting)

VIN: 5 V/div VEN: 3 V/div V_{OUT}: 2 V/div

Time: 1 ms/div

Figure 28. Shutdown at $R_{LOAD} = 0.66$ Ω: $V_{EN} = 5$ V to 0 V $(V_{IN} = 12 V, V_{OUT} = 3.3 V, C_{SS} = OPER,$ 1 MHz $_l$ loutmax = 5 A $_l$ LLM setting)

V_{PGD}: 5 V/div

Figure 30. Efficiency vs Output Current $(V_{IN} = 12 V, 600 kHz_{OUTMAX} = 5 A_PWM setting)$

Figure 32. Efficiency vs Output Current $(V_{IN} = 24 V, 600 kHz_{OUTMAX} = 5 A_{FWM}$ setting)

Figure 34. Efficiency vs Output Current $(V_{IN} = 12 V, 1 MHz_{OUTMAX} = 5 A_PWM setting)$

Figure 36. Efficiency vs Output Current $(V_{IN} = 24 V, 1 MHz_{OUTMAX} = 5 A_{FWM}$ setting)

Figure 38. Efficiency vs Output Current $(V_{IN} = 12 V, 600 kHz_{OUTMAX} = 3 A_PWM setting)$

Figure 40. Efficiency vs Output Current $(V_{IN} = 24 V, 600 kHz_{OUTMAX} = 3 A_PWM$ setting)

Figure 41. Efficiency vs Output Current $(V_{IN} = 12 V, 1 MHz_{OUTMAX} = 3 A_{LLM setting})$

Figure 42. Efficiency vs Output Current $(V_{IN} = 12 V, 1 MHz_{OUTMAX} = 3 A_PWM setting)$

Figure 44. Efficiency vs Output Current $(V_{IN} = 24 V, 1 MHz_{OUTMAX} = 3 A_PWM$ setting)

Figure 46. Load Regulation (V_{IN} = 12 V, V_{OUT} = 3.3 V, 600 kHz_ I_{OUTMAX} = 5 A setting)

Figure 48. Load Regulation (V_{IN} = 12 \check{V} , V_{OUT} = 3.3 V, 2.2 MHz setting)

Figure 49. Switching Frequency vs Output Current $(V_{IN} = 12 V, V_{OUT} = 3.3 V, 600 kHz_{OUTMAX} = 5 A setting)$

Figure 50. Switching Frequency vs Output Current $(V_{IN} = 12 V, V_{OUT} = 3.3 V, 1 MHz_{OUT}$ = 5 A setting)

Figure 52. Line Regulation $(\bar{V}_{OUT} = 3.3 \text{ V}, \bar{V}_{OUT} = 2 \text{ A},$ 600 kHz_ $I_{\text{OUTMAX}} = 5$ A_PWM setting)

Figure 53. Line Regulation $(V_{OUT} = 3.3 V, I_{OUT} = 2 A, 1 MHz_{OUT} = 5 A_PWM setting)$

Figure 54. Line regulation $(V_{OUT} = 3.3 V, I_{OUT} = 1 A, 2.2 MHz setting)$

Figure 56. Switching Frequency vs Input Voltage $(V_{OUT} = 3.3 V, I_{OUT} = 2 A, 1 MHz_{OUT}$ = 5 A_PWM setting)

Figure 57. Switching Frequency vs Input Voltage (V_{OUT} = 3.3 V, I_{OUT} = 1 A, 2.2 MHz setting)

Figure 58. Output Current vs Temperature*(Note 1)* Operating Range: Tj < 150 °C (V_{OUT} = 3.3 V, 600 kHz setting)

Figure 60. Output Current vs Temperature*(Note 1)* Operating Range: Tj < 150 °C (V_{OUT} = 3.3 V, 2.2 MHz setting)

(Note 1) Measured on FR-4 board 85 mm x 85 mm, Copper Thickness: Top and Bottom 70 μm, 2 Internal Layers 35 μm.

Function Explanations

1. Basic Operation

(1) DC/DC Converter Operation

BD9F500QUZ is a synchronous rectifying step-down switching regulator that has original On-Time control method. Device operates as the SEL1 pin and the SEL2 pin setting. When the operating mode is Light Load Mode, it utilizes switching operation in Pulse Width Modulation (PWM) mode control at heavier load, and it operates in Light Load mode (LLM) control at lighter load to improve efficiency. When the operating mode is Fixed PWM Mode, the device operates in PWM mode control regardless of the load.

Figure 61. Efficiency Image between Light Load Mode Control and PWM Mode Control

(2) Enable Control

The startup and shutdown can be controlled by the EN voltage (V_{EN}). When V_{EN} becomes 1.2 V (Typ) or more, the internal circuit is activated and the device starts up. When V_{EN} becomes 1.1 V (Typ) or less, the device is shutdown. In this shutdown mode, the High-Side FET and the Low-Side FET are turned off and the SW pin is connected to GND through an internal resistor 400 Ω (Typ) to discharge the output. The start-up with V_{EN} must be at the same time of the input voltage V_{IN} ($V_{IN} = V_{EN}$) or after supplying V_{IN} .

1. Basic Operation – continued

(3) Soft Start

When V_{EN} goes high, soft start function operates and output voltage gradually rises. This soft start function can prevent overshoot of the output voltage and excessive inrush current. The soft start time tss is 2 ms (Typ) when the SS pin is left floating. A capacitor connected to the SS pin makes tss more than 2 ms. See Selection of Components [Externally Connected 4. Soft Start Capacitor](#page-45-0) for how to set the soft start time.

Figure 63. Soft Start Timing Chart

1. Basic Operation – continued

(4) Power Good

When the output voltage V_{OUT} reaches within $±7$ % (Typ) of the voltage setting, the built-in open drain Nch MOSFET connected to the PGD pin is turned off, and the PGD pin goes Hi-Z (High impedance). When V_{OUT} reaches outside ±10 % (Typ) of the voltage setting, the open drain Nch MOSFET is turned on and PGD pin is pulled down with 500 Ω (Typ). It is recommended to connect a pull-up resistor of 20 kΩ to 100 kΩ.

Figure 64. Power Good Timing Chart (Connecting a pull-up resistor to the PGD pin)

(5) Nano Pulse ControlTM

Nano Pulse ControlTM is an original technology developed by ROHM Co., Ltd. It enables to control voltage stably, which is difficult in the conventional technology, even in a narrow SW ON time such as less than 50 ns at typical condition.

1. Basic Operation – continued

(6) Output Capacitor Discharge Function

When even one of the following conditions is satisfied, output is discharged with 400 Ω (Typ) resistor through the SW pin.

- Shutdown: $V_{EN} \leq 1.1$ V (Typ)
- \cdot UVLO: $V_{IN} \leq 4.0$ V (Typ)
- TSD: Tj ≥ 175 °C (Typ)
- OVP: V_{FB} / $V_{FBTH} \ge 120$ % (Typ)

When all of the above conditions are released, output discharge is stopped.

(7) Control Mode Selectable Function

BD9F500QUZ has the SEL1 pin and the SEL2 pin that can offer 9 different states of operation as a combination of Switching Frequency, Maximum Output Current and Operation mode. It can operate at two different current limits to support an output continuous current of 5 A, 3 A respectively. It can operate at three different frequencies of 600 kHz, 1 MHz and 2.2 MHz and also can choose between Light Load Mode and Fixed PWM mode for 600 kHz and 1 MHz operation. Do not change the mode control of Switching Frequency and Maximum Output Current during operation.

Function Explanations – continued

2. Protection

The protection circuits are intended for prevention of damage caused by unexpected accidents. Do not use the continuous protection.

(1) Over Current Protection (OCP) / Short Circuit Protection (SCP)

Over Current Protection (OCP) restricts the flowing current through the Low-Side FET and the High-Side FET for every switching period. If the inductor current exceeds the Low-Side OCP $I_{LOCP1} = 6.7$ A (Typ), $I_{LOCP2} = 4.0$ A (Typ) while the Low-Side FET is on, the Low-Side FET remains on even with FB voltage V_{FB} falls to $V_{FBTH} = 0.6$ V (Typ) or less. If the inductor current becomes less than I_{LOCP1}, I_{LOCP2}, the High-Side FET is able to be turned on. When the inductor current becomes the High-Side OCP I_{HOCP1} = 8.25 A (Typ), I_{HOCP2} = 5.0 A (Typ) or more while the High-Side FET is on, the High-Side FET is turned off. Output voltage may decrease by changing frequency and duty due to the OCP operation. Short Circuit Protection (SCP) function is a Hiccup mode. When Low-Side OCP 128 times is counted while V_{FB} is V_{FBTH} x 90 % or less (V_{PGD} = Low), the device stops the switching operation for 16 times of Soft Start Time (Typ). After that, the device restarts. SCP does not operate during the soft start even if the device is in the SCP conditions. Do not exceed the maximum junction temperature (Timax = 150 $^{\circ}$ C) during OCP and SCP operation.

Figure 65. OCP and SCP Timing Chart

2. Protection – continued

(2) Low-Side Sink (Reverse) Over Current Protection (ROCP)

When operating mode is Fixed PWM and inductor current exceeds the sink current limit threshold value $I_{ROCP1} = 4.2$ A (Typ), $I_{ROCP2} = 2.5$ A (Typ) while Low-Side FET is ON, the Low-Side FET turns OFF.

(3) Under Voltage Lockout Protection (UVLO)

When input voltage V_{IN} falls to 4.0 V (Typ) or less, the device is shutdown. When V_{IN} becomes 4.2 V (Typ) or more, the device starts up. The hysteresis is 200 mV (Typ).

(4) Thermal Shutdown Protection (TSD)

Thermal shutdown circuit prevents heat damage to the IC. The device should always operate within the IC's maximum junction temperature rating (Tjmax = 150 °C). However, if it continues exceeding the rating and the junction temperature Tj rises to 175 °C (Typ), the TSD circuit is activated and it turns the output MOSFETs off. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation. The TSD threshold has a hysteresis of 25 °C (Typ). Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings. Therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

(5) Over Voltage Protection (OVP)

When the FB voltage V_{FB} exceeds V_{FBTH} x 120 % (Typ) or more, output is discharged with 400 Ω (Typ) resister through the SW pin to prevent the increase in the output voltage. After the V_{FB} falls V_{FBTH} x 115 % (Typ) or less, the output MOSFETs are returned to normal operation condition. Switching operation restarts after V_{FB} falls below V_{FBTH} (Typ).

Application Examples

1. V_{IN} = 12 V to 24 V, V_{OUT} = 3.3 V, f_{SW} = 1 MHz

Table 5. Specification of Application

Parameter	Symbol	Specification Value		
Input Voltage	V _{IN}	12 V to 24 V (Typ)		
Output Voltage	V OUT	3.3 V (Typ)		
Maximum Output Current	I OUTMAX	5 A		
Switching Frequency	fsw	1 MHz (Typ)		
Operation Mode	$\overline{}$	Light Load Mode		
Temperature	Та	25 °C		

Table 6. Recommended Component Values

(Note 1) In order to reduce the influence of high frequency noise, connect a 0.1 μF ceramic capacitor C_{IN1} as close as possible to the VIN pin and the PGND pin. *(Note 2)* For the input capacitor C_{IN2}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 3 μF.

(Note 3) For the bootstrap capacitor C_{BOOT}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

(Note 4) In case of changing the actual capacitance value due to temperature characteristics, DC bias characteristics, etc. of the output capacitor C_{OUT1} and C_{OUT2}, the loop response characteristics may change. Confirm with the actual application.

(Note 5) For the VREG capacitor C_{REG}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

(Note 6) R₀ is an option, used for feedback's frequency response measurement. By inserting a resistor at R₀ it is possible to measure the frequency response (phase margin) using a FRA. However, the resistor is not used in actual application, use this resistor pattern in short-circuit mode.

1. V_{IN} = 12 V to 24 V, V_{OUT} = 3.3 V, f_{SW} = 1 MHz – continued

Figure 68. Efficiency vs Output Current Figure 69. Output Ripple Voltage (V_{IN} = 12 V, $I_{\text{OUT}} = 5 \text{ A}$)

Figure 70. Frequency Characteristics (V_{IN} = 12 V, I_{OUT} = 3 A) Figure 71. Load Transient Response

 $(V_{IN} = 12 V, I_{OUT} = 0.1 A to 3.0 A)$

Application Examples – continued

2. V_{IN} = 12 V to 24 V, V_{OUT} = 3.3 V, f_{SW} = 600 kHz

Table 7. Specification of Application

Parameter	Symbol	Specification Value				
Input Voltage	V _{IN}	12 V to 24 V (Typ)				
Output Voltage	VOUT	3.3 V (Typ)				
Maximum Output Current	I OUTMAX	5 A				
Switching Frequency	fsw	600 kHz (Typ)				
Operation Mode	$\overline{}$	Light Load Mode				
Temperature	Та	25 °C				

Figure 72. Application Circuit

(Note 1) In order to reduce the influence of high frequency noise, connect a 0.1 μF ceramic capacitor C_{IN1} as close as possible to the VIN pin and the PGND pin. *(Note 2)* For the input capacitor C_{IN2}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 3 μF.

(Note 3) For the bootstrap capacitor C_{BOOT}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

(Note 4) In case of changing the actual capacitance value due to temperature characteristics, DC bias characteristics, etc. of the output capacitor C_{OUT1} and C_{OUT2}, the loop response characteristics may change. Confirm with the actual application.

(Note 5) For the VREG capacitor C_{REG}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

(Note 6) R₀ is an option, used for feedback's frequency response measurement. By inserting a resistor at R₀ it is possible to measure the frequency response (phase margin) using a FRA. However, the resistor is not used in actual application, use this resistor pattern in short-circuit mode.

2. V_{IN} = 12 V to 24 V, V_{OUT} = 3.3 V, f_{SW} = 600 kHz – continued

Figure 73. Efficiency vs Output Current Figure 74. Output Ripple Voltage (V_{IN} = 12 V, $I_{\text{OUT}} = 5 \text{ A}$)

Figure 75. Frequency Characteristics (V_{IN} = 12 V, I_{OUT} = 3 A) Figure 76. Load Transient Response

 $(V_{IN} = 12 V, I_{OUT} = 0.1 A to 3.0 A)$

Application Examples – continued

3. $V_{IN} = 5 V$, $V_{OUT} = 3.3 V$, $f_{SW} = 1 MHz$

Figure 77. Application Circuit

Table 10. Recommended Component Values

(Note 1) In order to reduce the influence of high frequency noise, connect a 0.1 μF ceramic capacitor C_{IN1} as close as possible to the VIN pin and the PGND pin. *(Note 2)* For the input capacitor C_{IN2}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 3 μF.

(Note 3) For the bootstrap capacitor C_{BOOT}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

(Note 4) In case of changing the actual capacitance value due to temperature characteristics, DC bias characteristics, etc. of the output capacitor C_{OUT1} and C_{OUT2}, the loop response characteristics may change. Confirm with the actual application.

(Note 5) For the VREG capacitor C_{REG}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

(Note 6) R₀ is an option, used for feedback's frequency response measurement. By inserting a resistor at R₀ it is possible to measure the frequency response (phase margin) using a FRA. However, the resistor is not used in actual application, use this resistor pattern in short-circuit mode.

3. $V_{IN} = 5 V$, $V_{OUT} = 3.3 V$, $f_{SW} = 1 MHz$ – continued

Figure 78. Efficiency vs Output Current Figure 79. Output Ripple Voltage ($I_{\text{OUT}} = 5 \text{ A}$)

Figure 80. Frequency Characteristics ($I_{\text{OUT}} = 3 \text{ A}$) Figure 81. Load Transient Response ($I_{\text{OUT}} = 0.1 \text{ A}$ to 3.0 A)

Application Examples – continued

4. $V_{IN} = 5 V$, $V_{OUT} = 3.3 V$, $f_{SW} = 600 kHz$

Figure 82. Application Circuit

Table 12. Recommended Component Values

(Note 1) In order to reduce the influence of high frequency noise, connect a 0.1 μF ceramic capacitor C_{IN1} as close as possible to the VIN pin and the PGND pin. *(Note 2)* For the input capacitor C_{IN2}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 3 μF.

(Note 3) For the bootstrap capacitor C_{BOOT}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

(Note 4) In case of changing the actual capacitance value due to temperature characteristics, DC bias characteristics, etc. of the output capacitor C_{OUT1} and C_{OUT2}, the loop response characteristics may change. Confirm with the actual application.

(Note 5) For the VREG capacitor C_{REG}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

(Note 6) R₀ is an option, used for feedback's frequency response measurement. By inserting a resistor at R₀ it is possible to measure the frequency response (phase margin) using a FRA. However, the resistor is not used in actual application, use this resistor pattern in short-circuit mode.

4. $V_{IN} = 5 V$, $V_{OUT} = 3.3 V$, $f_{SW} = 600 kHz - continued$

Figure 83. Efficiency vs Output Current Figure 84. Output Ripple Voltage ($I_{\text{OUT}} = 5 \text{ A}$)

Figure 85. Frequency Characteristics ($I_{\text{OUT}} = 3 \text{ A}$) Figure 86. Load Transient Response ($I_{\text{OUT}} = 0.1 \text{ A}$ to 3.0 A)

Application Examples – continued

5. V_{IN} = 12 V, V_{OUT} = 1 V, f_{SW} = 1 MHz

Table 14. Recommended Component Values

(Note 1) In order to reduce the influence of high frequency noise, connect a 0.1 μF ceramic capacitor C_{IN1} as close as possible to the VIN pin and the PGND pin. *(Note 2)* For the input capacitor C_{IN2}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 3 μF.

(Note 3) For the bootstrap capacitor C_{BOOT}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

(Note 4) In case of changing the actual capacitance value due to temperature characteristics, DC bias characteristics, etc. of the output capacitor C_{OUT1} and C_{OUT2}, the loop response characteristics may change. Confirm with the actual application.

(Note 5) For the VREG capacitor C_{REG}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

(Note 6) R₀ is an option, used for feedback's frequency response measurement. By inserting a resistor at R₀ it is possible to measure the frequency response (phase margin) using a FRA. However, the resistor is not used in actual application, use this resistor pattern in short-circuit mode.

$5. V_{IN} = 12 V, V_{OUT} = 1 V, f_{SW} = 1 MHz - continued$

Figure 88. Efficiency vs Output Current Figure 89. Output Ripple Voltage ($I_{\text{OUT}} = 5 \text{ A}$)

Figure 90. Frequency Characteristics ($I_{\text{OUT}} = 3 \text{ A}$) Figure 91. Load Transient Response ($I_{\text{OUT}} = 0 \text{ A}$ to 3 A)

Application Examples – continued

6. V_{IN} = 12 V, V_{OUT} = 1 V, f_{SW} = 600 kHz

Figure 92. Application Circuit

Table 16. Recommended Component Values

(Note 1) In order to reduce the influence of high frequency noise, connect a 0.1 μF ceramic capacitor C_{IN1} as close as possible to the VIN pin and the PGND pin. *(Note 2)* For the input capacitor C_{IN2}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 3 μF.

(Note 3) For the bootstrap capacitor C_{BOOT}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

(Note 4) In case of changing the actual capacitance value due to temperature characteristics, DC bias characteristics, etc. of the output capacitor C_{OUT1} and C_{OUT2}, the loop response characteristics may change. Confirm with the actual application.

(Note 5) For the VREG capacitor C_{REG}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

(Note 6) R₀ is an option, used for feedback's frequency response measurement. By inserting a resistor at R₀ it is possible to measure the frequency response (phase margin) using a FRA. However, the resistor is not used in actual application, use this resistor pattern in short-circuit mode.

6. V_{IN} = 12 V, V_{OUT} = 1 V, f_{SW} = 600 kHz – continued

Figure 93. Efficiency vs Output Current Figure 94. Output Ripple Voltage ($I_{\text{OUT}} = 5 \text{ A}$)

Figure 95. Frequency Characteristics ($I_{\text{OUT}} = 3 \text{ A}$) Figure 96. Load Transient Response ($I_{\text{OUT}} = 0 \text{ A}$ to 3 A)

Application Examples – continued

7. V_{IN} = 12 V, V_{OUT} = 3.3 V, f_{SW} = 2.2 MHz

Figure 97. Application Circuit

Table 18. Recommended Component Values

(Note 1) In order to reduce the influence of high frequency noise, connect a 0.1 μF ceramic capacitor C_{IN1} as close as possible to the VIN pin and the PGND pin. *(Note 2)* For the input capacitor C_{IN2}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 3 μF.

(Note 3) For the bootstrap capacitor C_{BOOT}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

(Note 4) In case of changing the actual capacitance value due to temperature characteristics, DC bias characteristics, etc. of the output capacitor C_{OUT1} and C_{OUT2}, the loop response characteristics may change. Confirm with the actual application.

(Note 5) For the VREG capacitor C_{REG}, take temperature characteristics, DC bias characteristics, etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

(Note 6) R₀ is an option, used for feedback's frequency response measurement. By inserting a resistor at R₀ it is possible to measure the frequency response (phase margin) using a FRA. However, the resistor is not used in actual application, use this resistor pattern in short-circuit mode.

Figure 98. Efficiency vs Output Current Figure 99. Output Ripple Voltage ($I_{\text{OUT}} = 3 \text{ A}$)

Figure 100. Frequency Characteristics ($I_{OUT} = 2 A$) Figure 101. Load Transient Response ($I_{OUT} = 0 A$ to 2 A)

Selection of Components Externally Connected

Contact us if not use the recommended component values i[n Application Examples.](#page-28-0)

1. Input Capacitor

Use ceramic type capacitor for the input capacitor. The input capacitor is used to reduce the input ripple noise and it is effective by being placed as close as possible to the VIN pin. Set the capacitor value so that it does not fall to 3 μF considering the capacitor value variances, temperature characteristics, DC bias characteristics, aging characteristics, and etc. The PCB layout and the position of the capacitor may lead to IC malfunction. Refer to the notes on the PCB layout on [PCB Layout Design](#page-46-0) when designing PCB layout. In addition, the capacitor with value 0.1 μ F can be connected as close as possible to the VIN pin and the PGND pin in order to reduce the high frequency noise.

2. Output LC Filter

In order to supply a continuous current to the load, the DC/DC converter requires an LC filter for smoothing the output voltage. For recommended inductance, use the values listed in Table 19.

Figure 102. Waveform of Inductor Current Figure 103. Output LC Filter Circuit

For example, given that V_{IN} = 12 V, V_{OUT} = 3.3 V, L = 1.5 µH, and the switching frequency f_{SW} = 1.0 MHz, Inductor current ΔI^L can be represented by the following equation.

$$
\Delta I_L = V_{OUT} \times (V_{IN} - V_{OUT}) \times \frac{1}{V_{IN} \times f_{SW} \times L} = 1.595 \text{ [A]}
$$

The rated current of the inductor (Inductor saturation current) must be larger than the sum of the maximum output current IOUTMAX and 1/2 of the inductor ripple current ΔIL.

Use ceramic type capacitor for the output capacitor C_{OUT} . For recommended actual capacitance, use the values listed in Table 19. C_{OUT} affects the output ripple voltage. Select C_{OUT} so that it must satisfy the required ripple voltage characteristics.

The output ripple voltage can be estimated by the following equation.

$$
\Delta V_{RPL} = \Delta I_L \times \left(R_{ESR} + \frac{1}{8 \times C_{OUT} \times f_{SW}}\right) \text{ [V]}
$$

where:

 R_{ESR} is the Equivalent Series Resistance (ESR) of the output capacitor.

For example, given that $C_{\text{OUT}} = 44 \mu F$ and $R_{\text{ESR}} = 3 \text{ m}\Omega$, ΔV_{RPL} can be calculated as below.

$$
\Delta V_{RPL} = 1.595 A \times \left(3 \, m\Omega + \frac{1}{8 \times 44 \, \mu F \times 1 \, MHz}\right) = 9.3 \, \text{[mV]}
$$

2. Output LC Filter – continued

In addition, the total capacitance connected to V_{OUT} needs to satisfy the value obtained by the following equation.

$$
C_{OUTMAX} < \frac{t_{SSMIN}}{v_{OUT}} \times (I_{OUTMAX} + \frac{\Delta I_L}{2} - I_{OUTSS}) \text{ [F]}
$$

where:

 t_{SSMIN} is the minimum soft start time. V_{OUT} is the output voltage. I_{OUTMAX} is the maximum output current. ΔI_L is the inductor current. I_{OUTSS} is the maximum output current during soft start.

For example, given that $V_{\text{IN}} = 12$ V, $V_{\text{OUT}} = 3.3$ V, L = 1.5 µH, f_{SW} = 1 MHz (Typ), t_{SSMIN} = 1.4 ms (C_{SS} = OPEN), $I_{\text{OUTMAX}} = 5$ A, and $I_{\text{OUTSS}} = 5$ A, C_{OUTMAX} can be calculated as below.

$$
C_{OUTMAX} < \frac{1.4 \, \text{ms}}{3.3 \, \text{V}} \times (5 \, \text{A} + \frac{1.595 \, \text{A}}{2} - 5 \, \text{A}) = 338 \, \text{ [µF]}
$$

If the total capacitance connected to V_{OUT} is larger than C_{OUTMAX} , over current protection may be activated by the inrush current at startup and prevented to turn on the output. Confirm this on the actual application.

Table 19. Recommended inductance and output capacitance

(Note 1) $C_{\text{OUT EFF}}$ is the sum of actual output capacitance.

Selection of Components Externally Connected – continued

3. Output Voltage Setting, FB Capacitor

The output voltage can be set by the feedback resistance ratio connected to the FB pin. For recommended R_1 and R_2 , use the values listed in Table 20.

The output voltage V_{OUT} can be calculated as below.

$$
V_{OUT} = \frac{R_1 + R_2}{R_2} \times 0.6 \text{ [V]}
$$

$$
0.6 \le V_{OUT} \le 14 \text{ [V]}
$$

 $V_{OUT} \le (V_{IN} \times 0.8)$ [V]

Figure 104. Feedback Resistor Circuit

The Constant On-Time control required the sufficient ripple voltage on FB voltage for the operation stability. This device is designed to correspond to low ESR output capacitors by injecting the ripple voltage to FB voltage inside the IC. The FB capacitor C_{FB} should be set with the following expression as typical value in order to inject an appropriate ripple. For recommended C_{FB} , use the values listed in Table 20.

600 kHz setting

$$
C_{FB} = \frac{V_{OUT} \times (1 - V_{OUT}/V_{IN})}{f_{SW} \times 5.25 \times 10^4}
$$
 [F]

where: V_{IN} is the input voltage. V_{OUT} is the output voltage. f_{SW} is the switching frequency 600 kHz (Typ).

1MHz, 2.2MHz setting

$$
C_{FB} = \frac{V_{OUT} \times (1 - V_{OUT}/V_{IN})}{f_{SW} \times 3.5 \times 10^4}
$$
 [F]

where: V_{IN} is the input voltage. V_{OUT} is the output voltage. f_{SW} is the switching frequency 1 MHz, 2.2 MHz (Typ).

Load transient response and the loop stability depends on L, C_{OUT} , R₁, R₂, and C_{FE} . Actually, these characteristics may change depending on PCB layout, wiring, the type of components, and the conditions (temperature, etc.). Be sure to check them on the actual application.

3. Output Voltage Setting, FB Capacitor – continued

Table 20. Recommended reedback resistance, C _{FB} capacitance								
Frequency [MHz]	V_{IN} [V]	VOUT ^[V]	R_1 [kΩ]	R_2 [kΩ]	C_{FB} [pF]			
0.6	12	3.3	$1.5 + 120$	27	82			
0.6	24	3.3	$1.5 + 120$	27	82			
0.6	5	3.3	$120 + 330$	100	39			
0.6	12	1	180	270	33			
0.6	5	1	180	270	27			
0.6	12	5	220	30	100			
0.6	24	5	220	30	100			
0.6	24	12	$68 + 560$	33	180			
1	12	3.3	$1.5 + 120$	27	82			
1	24	3.3	$1.5 + 120$	27	82			
1	5	3.3	$120 + 330$	100	33			
1	12	1	180	270	27			
1	5	1	180	270	22			
1	12	5	220	30	100			
1	24	5	220	30	100			
1	24	12	$68 + 560$	33	180			
2.2	12	3.3	$1.5 + 120$	27	33			
2.2	24	3.3	$1.5 + 120$	27	33			

 $Table 20. Boommanded feedback projections, C. 20020$

4. Soft Start Capacitor (Soft Start Time Setting)

The soft start time t_{SS} depends on the value of the capacitor connected to the SS pin. The t_{SS} is 2 ms (Typ) when the SS pin is left floating. The capacitor connected to the SS pin makes tss more than 2 ms. The tss and Css can be calculated using below equation. The C_{SS} should be set in the range between 0.01 µF and 0.1 µF.

$$
t_{SS} = \frac{c_{SS} \times 0.6 \times 1.3}{I_{SS}} \text{ [s]}
$$

where:

 I_{SS} is the Soft Start Charge Current 2.0 μ A (Typ).

With $C_{SS} = 0.022 \mu F$, t_{SS} can be calculated as below.

$$
t_{SS} = \frac{0.022 \,\mu F \times 0.6 \times 1.3}{2.0 \,\mu A} = 8.58 \,\text{[ms]}
$$

5. VREG Capacitor

The VREG capacitor 2.2 μF is recommended. Connect the capacitor between the VREG pin and the AGND pin. For the capacitance, take temperature characteristics, DC bias characteristics, and etc. into consideration to set to the actual capacitance of no less than 0.82 μF.

6. Bootstrap Capacitor

The bootstrap capacitor 0.1 μF is recommended. Connect the capacitor between the SW pin and the BOOT pin. For the capacitance, take temperature characteristics, DC bias characteristics, and etc. into consideration to set to the actual capacitance of no less than 0.022 μF.

PCB Layout Design

PCB layout design for DC/DC converter is very important. Appropriate layout can avoid various problems concerning power supply circuit. Figure 105-a to Figure 105-c show the current path in a buck DC/DC converter circuit. The Loop 1 in Figure 105-a is a current path when H-side switch is ON and L-side switch is OFF, the Loop 2 in Figure 105-b is when H-side switch is OFF and L-side switch is ON. The thick line in Figure 105-c shows the difference between Loop1 and Loop2. The current in thick line change sharply each time the switching element H-side and L-side switch change from OFF to ON, and vice versa. These sharp changes induce a waveform with harmonics in this loop. Therefore, the loop area of thick line that is consisted by input capacitor and IC should be as small as possible to minimize noise. For more details, refer to application note of switching regulator series "PCB Layout Techniques of Buck Converter".

Figure 105-a. Current Path when H-side Switch = ON, L-side Switch = OFF

Figure 105-b. Current Path when H-side Switch = OFF, L-side Switch = ON

Figure 105-c. Difference of Current and Critical Area in Layout

PCB Layout Design – continued

When designing the PCB layout, pay attention to the following points:

- Connect the input capacitor C_{IN1} and C_{IN2} as close as possible to the VIN pin and the PGND pin on the same plane as the IC.
- Switching nodes such as SW are susceptible to noise due to AC coupling with other nodes. Route the inductor pattern L as thick and as short as possible.
- The feedback line connected to the FB pin should be as far away from the SW nodes as possible.
- Place the output capacitor C_{OUT} away from input capacitor C_{IN1} and C_{IN2} to avoid harmonics noise from the input.
- Separate the reference ground and the power ground and connect them through VIA. The reference ground should be connected to the power ground that is close to the output capacitor C_{OUT} . It is because C_{OUT} has less high frequency switching noise.
- To provide excellent heat dissipation characteristics connect the VIN pins to the PCB VIN pattern by using thermal vias.
- Place the bypass capacitor between the VREG and AGND pins at a position as close as possible to the pin.
- When the SEL1 and SEL2 pins are left open, the parasitic capacitance with the VIN, SW, and BOOT pins should be 0.2 pF or less.
- R_0 is provided for the measurement of feedback frequency characteristics (optional). By inserting a resistor into R_0 , it is possible to measure the frequency characteristics of feedback (phase margin) using FRA etc. R_0 is short-circuited for normal use.

PCB Layout Design – continued

I/O Equivalence Circuits

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition. However, pins that drive inductive loads (e.g. motor driver outputs, DC-DC converter outputs) may inevitably go below ground due to back EMF or electromotive force. In such cases, the user should make sure that such voltages going below ground will not cause the IC and the system to malfunction by examining carefully all relevant factors and conditions such as motor characteristics, supply voltage, operating frequency and PCB wiring to name a few.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

Figure 108. Example of Monolithic IC Structure

11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

12. Thermal Shutdown Circuit (TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

13. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

Ordering Information

Marking Diagram

Revision History

Notice

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